

## Automotive N-Channel 40 V (D-S) 175 °C MOSFET

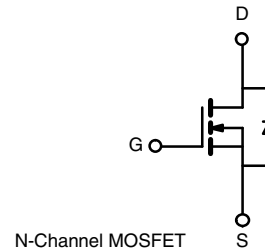
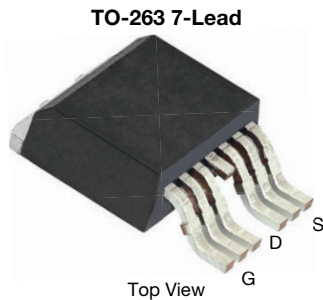


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

| PRODUCT SUMMARY                               |           |
|---|-----------|
| $V_{DS}$ (V)                                  | 40        |
| $R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 10$ V  | 0.0017    |
| $R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 4.5$ V | 0.0020    |
| $I_D$ (A)                                     | 200       |
| Configuration                                 | Single    |
| Package                                       | TO-263-7L |

### FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 %  $R_g$  and UIS tested
- AEC-Q101 qualified <sup>d</sup>
- Material categorization:  
for definitions of compliance please see  
[www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



| ABSOLUTE MAXIMUM RATINGS ( $T_C = 25$ °C, unless otherwise noted) |                            |                |             |      |
|---|----------------------------|----------------|-------------|------|
| PARAMETER   |                            | SYMBOL         | LIMIT       | UNIT |
| Drain-Source Voltage  |                            | $V_{DS}$       | 40          | V    |
| Gate-Source Voltage   |                            | $V_{GS}$       | $\pm 20$    |      |
| Continuous Drain Current  | $T_C = 25$ °C <sup>a</sup> | $I_D$          | 200         | A    |
|   | $T_C = 125$ °C             |                | 193         |      |
| Continuous Source Current (Diode Conduction) <sup>a</sup>         |                            | $I_S$          | 200         |      |
| Pulsed Drain Current <sup>b</sup>                                 |                            | $I_{DM}$       | 600         |      |
| Single Pulse Avalanche Current                                    | L = 0.1 mH                 | $I_{AS}$       | 95          |      |
| Single Pulse Avalanche Energy                                     |                            | $E_{AS}$       | 451         |      |
| Maximum Power Dissipation <sup>b</sup>                            | $T_C = 25$ °C              | $P_D$          | 375         | W    |
|   | $T_C = 125$ °C             |                | 125         |      |
| Operating Junction and Storage Temperature Range                  |                            | $T_J, T_{stg}$ | -55 to +175 | °C   |

| THERMAL RESISTANCE RATINGS |                        |            |       |      |
|----------------------------|------------------------|------------|-------|------|
| PARAMETER                  |                        | SYMBOL     | LIMIT | UNIT |
| Junction-to-Ambient        | PCB Mount <sup>c</sup> | $R_{thJA}$ | 40    | °C/W |
| Junction-to-Case (Drain)   |                        | $R_{thJC}$ | 0.4   |      |

### Notes

- Package limited.
- Pulse test; pulse width  $\leq 300$   $\mu$ s, duty cycle  $\leq 2$  %.
- When mounted on 1" square PCB (FR4 material).
- Parametric verification ongoing.



| SPECIFICATIONS ( $T_C = 25\text{ }^\circ\text{C}$ , unless otherwise noted) |              |   |  |      |        |           |               |
|---|--------------|---|--|------|--------|-----------|---------------|
| PARAMETER   | SYMBOL       | TEST CONDITIONS   |  | MIN. | TYP.   | MAX.      | UNIT          |
| <b>Static</b>   |              |   |  |      |        |           |               |
| Drain-Source Breakdown Voltage  | $V_{DS}$     | $V_{GS} = 0\text{ V}$ , $I_D = 250\text{ }\mu\text{A}$  |  | 40   | -      | -         | V             |
| Gate-Source Threshold Voltage   | $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 250\text{ }\mu\text{A}$  |  | 1.5  | 2.0    | 2.5       |               |
| Gate-Source Leakage   | $I_{GSS}$    | $V_{DS} = 0\text{ V}$ , $V_{GS} = \pm 20\text{ V}$  |  | -    | -      | $\pm 100$ | nA            |
| Zero Gate Voltage Drain Current   | $I_{DSS}$    | $V_{GS} = 0\text{ V}$   | $V_{DS} = 40\text{ V}$                                     | -    | -      | 1         | $\mu\text{A}$ |
|   |              | $V_{GS} = 0\text{ V}$   | $V_{DS} = 40\text{ V}$ , $T_J = 125\text{ }^\circ\text{C}$ | -    | -      | 50        |               |
|   |              | $V_{GS} = 0\text{ V}$   | $V_{DS} = 40\text{ V}$ , $T_J = 175\text{ }^\circ\text{C}$ | -    | -      | 250       |               |
| On-State Drain Current <sup>a</sup>   | $I_{D(on)}$  | $V_{GS} = 10\text{ V}$  | $V_{DS} \geq 5\text{ V}$                                   | 200  | -      | -         | A             |
| Drain-Source On-State Resistance <sup>a</sup>                               | $R_{DS(on)}$ | $V_{GS} = 10\text{ V}$  | $I_D = 30\text{ A}$  | -    | 0.0012 | 0.0017    | $\Omega$      |
|   |              | $V_{GS} = 10\text{ V}$  | $I_D = 30\text{ A}$ , $T_J = 125\text{ }^\circ\text{C}$    | -    | -      | 0.0028    |               |
|   |              | $V_{GS} = 10\text{ V}$  | $I_D = 30\text{ A}$ , $T_J = 175\text{ }^\circ\text{C}$    | -    | -      | 0.0034    |               |
|   |              | $V_{GS} = 4.5\text{ V}$   | $I_D = 20\text{ A}$  | -    | 0.0014 | 0.0020    |               |
| Forward Transconductance <sup>b</sup>                                       | $g_{fs}$     | $V_{DS} = 15\text{ V}$ , $I_D = 30\text{ A}$  |  | -    | 181    | -         | S             |
| <b>Dynamic <sup>b</sup></b>   |              |   |  |      |        |           |               |
| Input Capacitance   | $C_{iss}$    | $V_{GS} = 0\text{ V}$   | $V_{DS} = 20\text{ V}$ , $f = 1\text{ MHz}$                | -    | 8934   | 11 168    | $\text{pF}$   |
| Output Capacitance  | $C_{oss}$    |   |  | -    | 1592   | 1990      |               |
| Reverse Transfer Capacitance  | $C_{rss}$    |   |  | -    | 928    | 1160      |               |
| Total Gate Charge <sup>c</sup>  | $Q_g$        | $V_{GS} = 10\text{ V}$  | $V_{DS} = 20\text{ V}$ , $I_D = 20\text{ A}$               | -    | 194    | 291       | $\text{nC}$   |
| Gate-Source Charge <sup>c</sup>   | $Q_{gs}$     |   |  | -    | 25     | -         |               |
| Gate-Drain Charge <sup>c</sup>  | $Q_{gd}$     |   |  | -    | 40     | -         |               |
| Gate Resistance   | $R_g$        | $f = 1\text{ MHz}$  |  | 0.25 | 0.8    | 1.8       | $\Omega$      |
| Turn-On Delay Time <sup>c</sup>   | $t_{d(on)}$  | $V_{DD} = 20\text{ V}$ , $R_L = 1\text{ }\Omega$<br>$I_D \cong 20\text{ A}$ , $V_{GEN} = 10\text{ V}$ , $R_g = 1\text{ }\Omega$ |  | -    | 22     | 33        | $\text{ns}$   |
| Rise Time <sup>c</sup>  | $t_r$        |   |  | -    | 17     | 26        |               |
| Turn-Off Delay Time <sup>c</sup>  | $t_{d(off)}$ |   |  | -    | 70     | 105       |               |
| Fall Time <sup>c</sup>  | $t_f$        |   |  | -    | 16     | 24        |               |
| <b>Source-Drain Diode Ratings and Characteristics <sup>b</sup></b>          |              |   |  |      |        |           |               |
| Pulsed Current <sup>a</sup>   | $I_{SM}$     |   |  | -    | -      | 600       | A             |
| Forward Voltage   | $V_{SD}$     | $I_F = 60\text{ A}$ , $V_{GS} = 0\text{ V}$   |  | -    | 0.8    | 1.5       | V             |

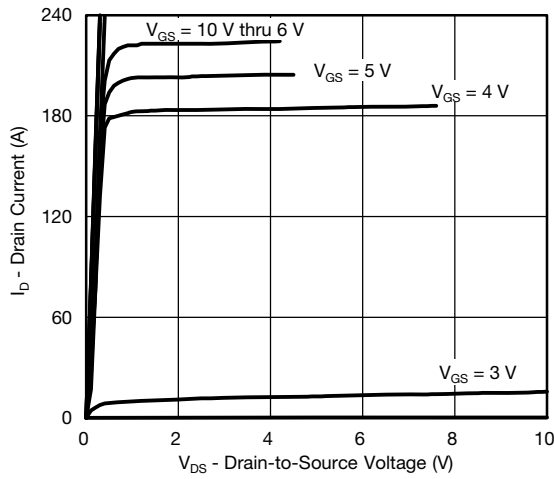
**Notes**

- Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

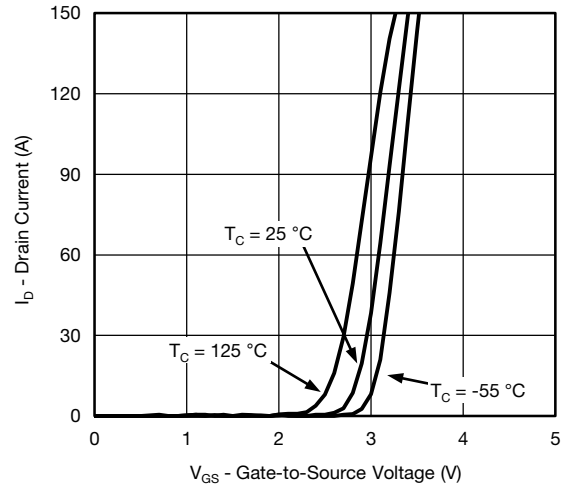
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



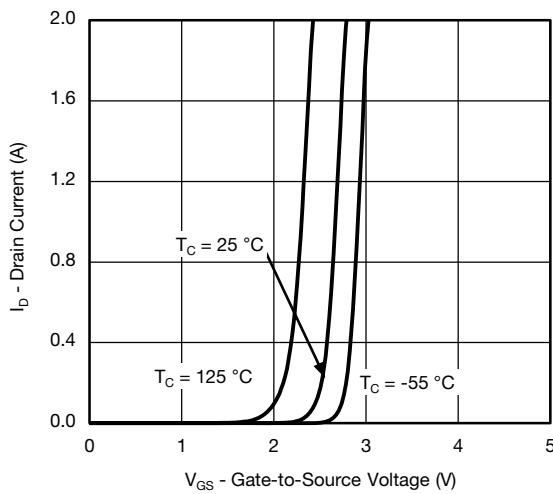
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



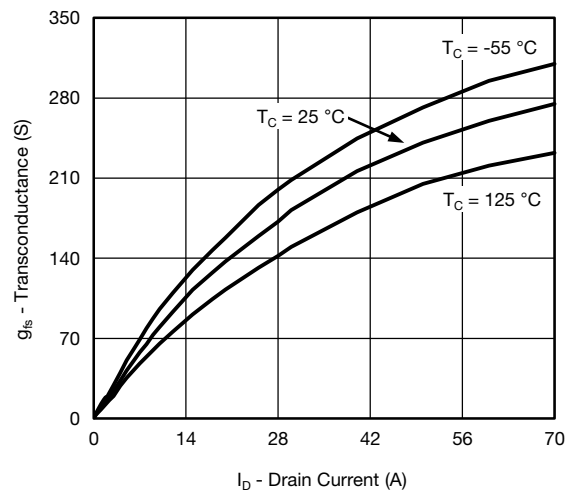
Output Characteristics



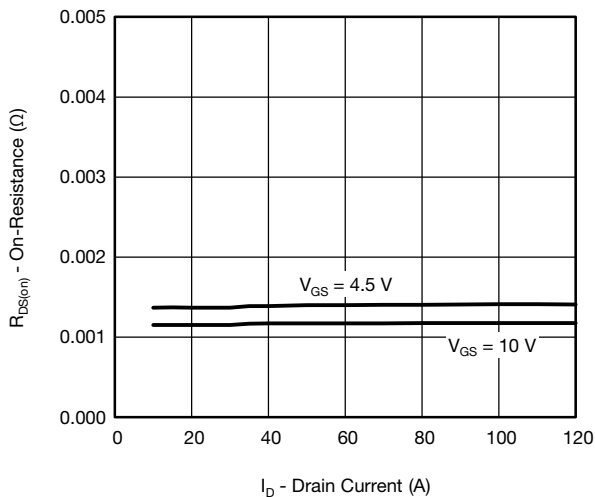
Transfer Characteristics



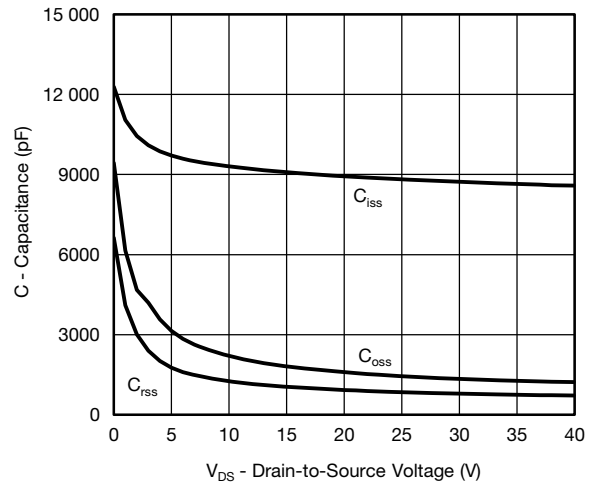
Transfer Characteristics



Transconductance



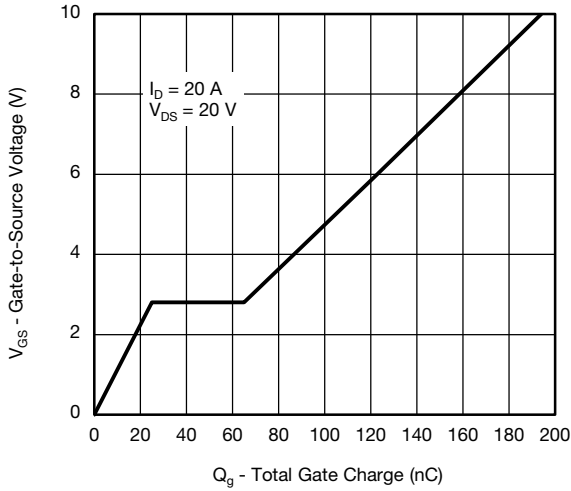
On-Resistance vs. Drain Current



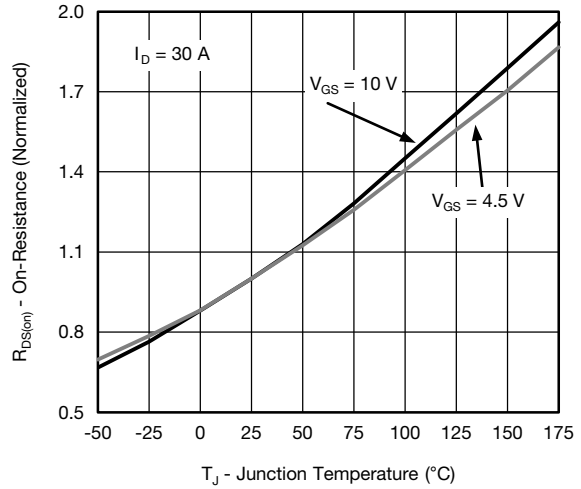
Capacitance



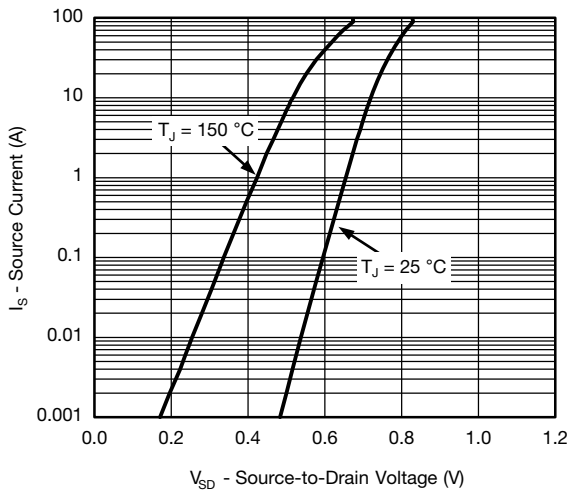
**TYPICAL CHARACTERISTICS** ( $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted)



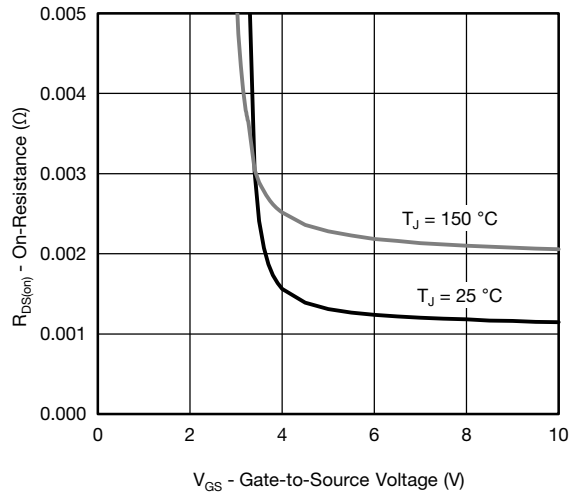
**Gate Charge**



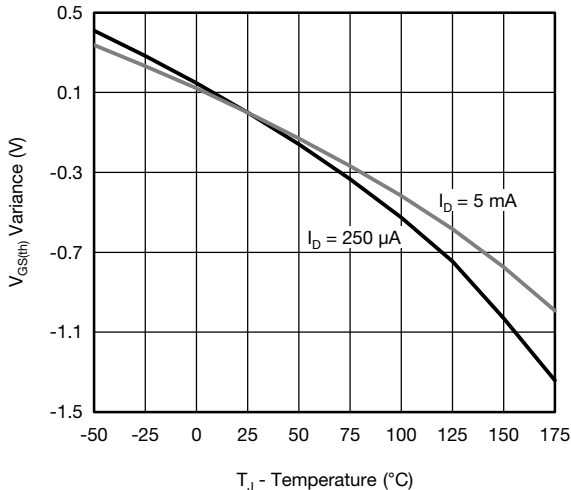
**On-Resistance vs. Junction Temperature**



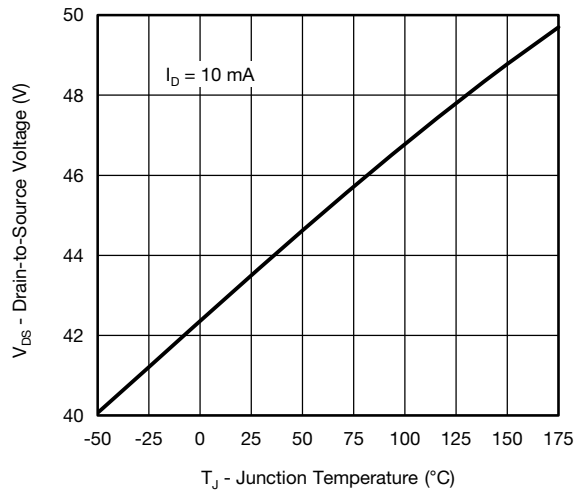
**Source Drain Diode Forward Voltage**



**On-Resistance vs. Gate-to-Source Voltage**



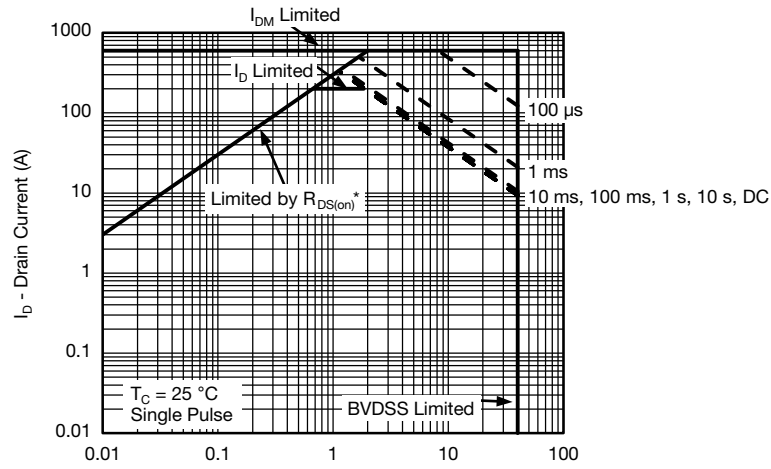
**Threshold Voltage**



**Drain Source Breakdown vs. Junction Temperature**

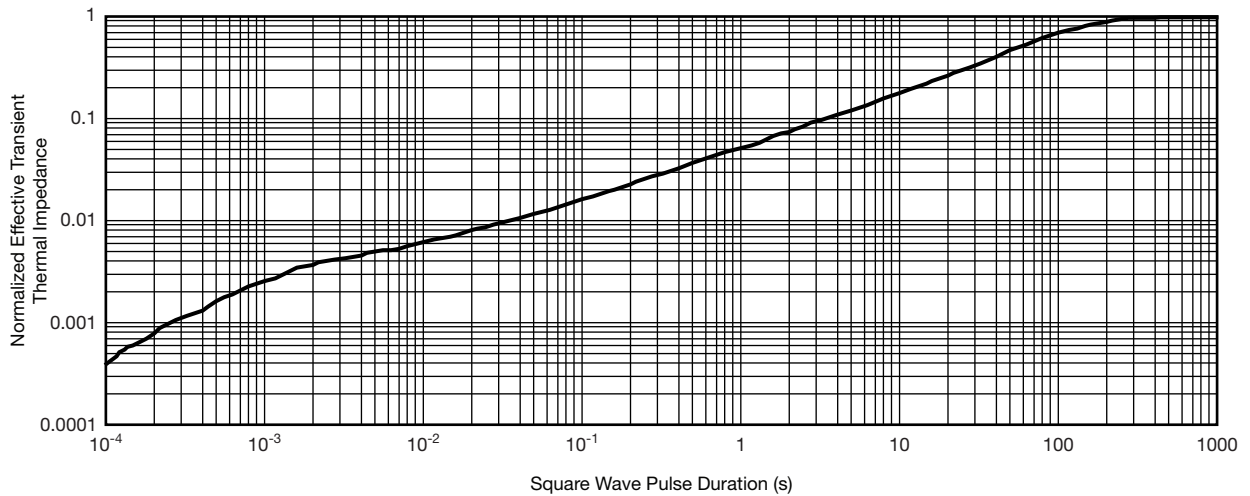


**THERMAL RATINGS** ( $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted)



\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

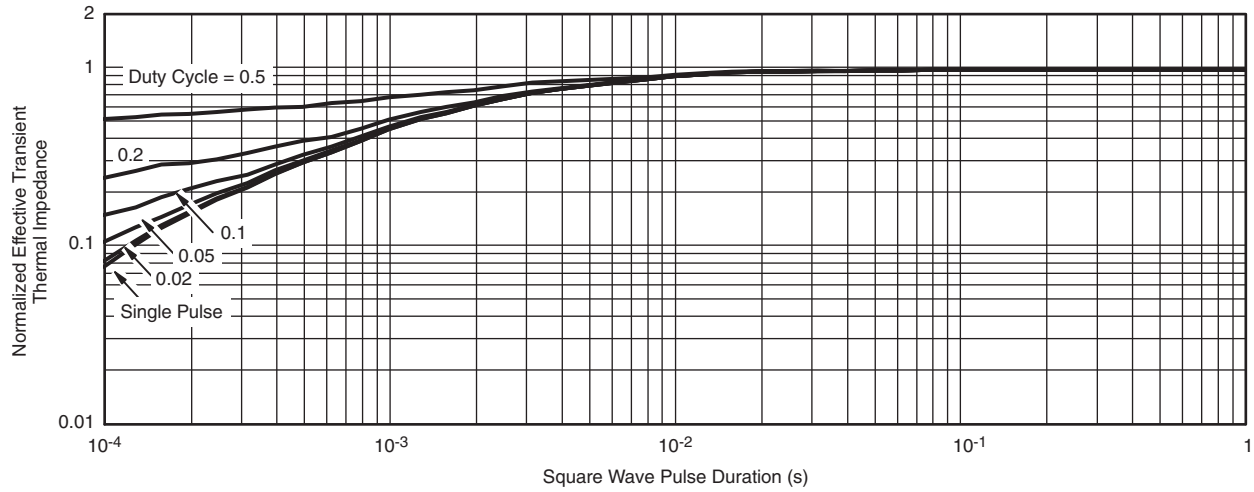
**Safe Operating Area**



**Normalized Thermal Transient Impedance, Junction-to-Ambient**



**THERMAL RATINGS** ( $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted)



**Normalized Thermal Transient Impedance, Junction-to-Case**

**Note**

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?67058](http://www.vishay.com/ppg?67058).



| REVISION HISTORY <sup>a</sup> |           |  |
|-------------------------------|-----------|--|
| REVISION                      | DATE      | DESCRIPTION OF CHANGE                  |
| B                             | 04-Aug-15 | • Revised R <sub>g</sub> minimum limit |

**Note**

a. As of April 2014



D<sup>2</sup>PAK / TO-263 and TO-262

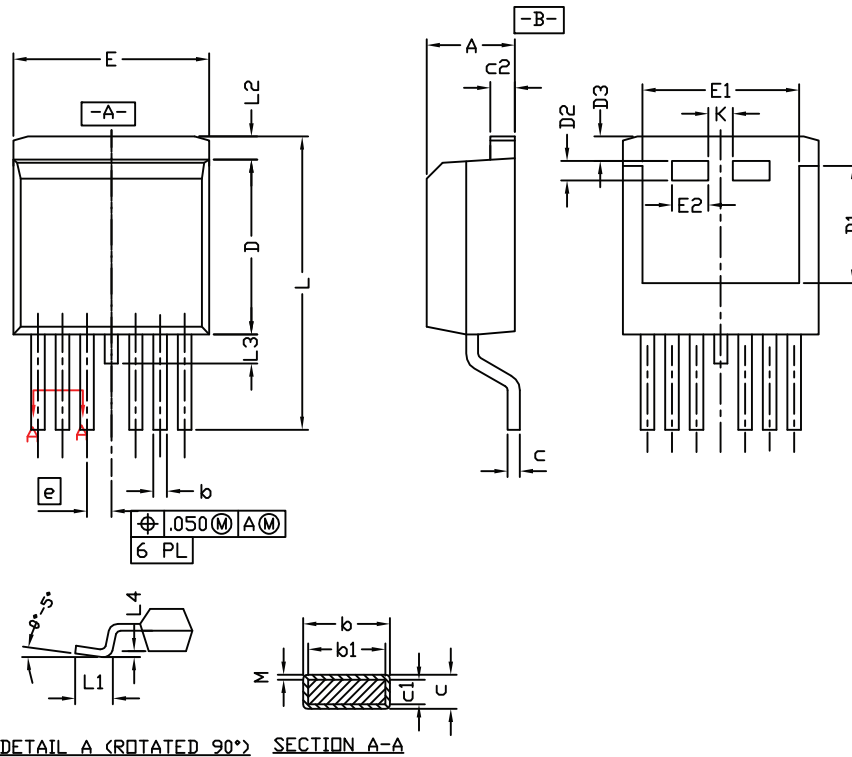
Ordering codes for the SQ rugged series power MOSFETs in the D<sup>2</sup>PAK / TO-263 and TO-262 packages:

| DATASHEET PART NUMBER | OLD ORDERING CODE <sup>a</sup> | NEW ORDERING CODE  |
|-----------------------|--------------------------------|--------------------|
| SQM100N04-2m7         | SQM100N04-2M7-GE3              | SQM100N04-2M7_GE3  |
| SQM100N10-10          | SQM100N10-10-GE3               | SQM100N10-10_GE3   |
| SQM110N05-06L         | SQM110N05-06L-GE3              | SQM110N05-06L_GE3  |
| SQM110P06-8m9L        | SQM110P06-8M9L-GE3             | SQM110P06-8M9L_GE3 |
| SQM120N02-1m3L        | SQM120N02-1M3L-GE3             | SQM120N02-1M3L_GE3 |
| SQM120N03-1m5L        | SQM120N03-1M5L-GE3             | SQM120N03-1M5L_GE3 |
| SQM120N04-1m7         | SQM120N04-1M7-GE3              | SQM120N04-1M7_GE3  |
| SQM120N04-1m7L        | SQM120N04-1M7L-GE3             | SQM120N04-1M7L_GE3 |
| SQM120N04-1m9         | SQM120N04-1M9-GE3              | SQM120N04-1M9_GE3  |
| SQM120N06-06          | SQM120N06-06-GE3               | SQM120N06-06_GE3   |
| SQM120N06-3m5L        | SQM120N06-3M5L-GE3             | SQM120N06-3M5L_GE3 |
| SQM120N10-09          | SQM120N10-09-GE3               | SQM120N10-09_GE3   |
| SQM120N10-3m8         | SQM120N10-3M8-GE3              | SQM120N10-3M8_GE3  |
| SQM120P04-04L         | SQM120P04-04L-GE3              | SQM120P04-04L_GE3  |
| SQM120P06-07L         | SQM120P06-07L-GE3              | SQM120P06-07L_GE3  |
| SQM200N04-1m1L        | SQM200N04-1M1L-GE3             | SQM200N04-1M1L_GE3 |
| SQM200N04-1m7L        | SQM200N04-1M7L-GE3             | SQM200N04-1M7L_GE3 |
| SQM200N04-1m8         | SQM200N04-1M8-GE3              | SQM200N04-1M8_GE3  |
| SQM25N15-52           | SQM25N15-52-GE3                | SQM25N15-52_GE3    |
| SQM35N30-97           | SQM35N30-97-GE3                | SQM35N30-97_GE3    |
| SQM40N10-30           | SQM40N10-30-GE3                | SQM40N10-30_GE3    |
| SQM40N15-38           | SQM40N15-38-GE3                | SQM40N15-38_GE3    |
| SQM40P10-40L          | SQM40P10-40L-GE3               | SQM40P10-40L_GE3   |
| SQM47N10-24L          | SQM47N10-24L-GE3               | SQM47N10-24L_GE3   |
| SQM50020EL            | -                              | SQM50020EL_GE3     |
| SQM50N04-4m0L         | SQM50N04-4M0L-GE3              | SQM50N04-4M0L_GE3  |
| SQM50N04-4m1          | SQM50N04-4M1-GE3               | SQM50N04-4M1_GE3   |
| SQM50P03-07           | SQM50P03-07-GE3                | SQM50P03-07_GE3    |
| SQM50P04-09L          | SQM50P04-09L-GE3               | SQM50P04-09L_GE3   |
| SQM50P06-15L          | SQM50P06-15L-GE3               | SQM50P06-15L_GE3   |
| SQM50P08-25L          | SQM50P08-25L-GE3               | SQM50P08-25L_GE3   |
| SQM60N06-15           | SQM60N06-15-GE3                | SQM60N06-15_GE3    |
| SQM60N20-35           | SQM60N20-35-GE3                | SQM60N20-35_GE3    |
| SQM85N15-19           | SQM85N15-19-GE3                | SQM85N15-19_GE3    |
| SQV120N10-3m8         | SQV120N10-3m8-GE3              | SQV120N10-3m8_GE3  |
| SQV120N06-4m7L        | -                              | SQV120N06-4m7L_GE3 |

Note

a. Old ordering code is obsolete and no longer valid for new orders

## D<sup>2</sup>PAK (TO-263-7L) Case Outline



### Notes

1. Plane B includes maximum features of heat sink tab and plastic.
2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
3. Pin to pin coplanarity max. 4 mils.
4. Lead thickness 25 mils.
5. For SUM part numbers lead thickness is 24 mils to 29 mils.
6. For reference only.
7. Use inches as the primary measurement.
8. This feature is only for SUM.

| DIM.                            | INCHES    |       | MILLIMETERS |        |
|---------------------------------|-----------|-------|-------------|--------|
|                                 | MIN.      | MAX.  | MIN.        | MAX.   |
| A                               | 0.160     | 0.190 | 4.064       | 4.826  |
| b                               | 0.020     | 0.039 | 0.508       | 0.990  |
| b1                              | 0.020     | 0.035 | 0.508       | 0.889  |
| b2                              | 0.045     | 0.055 | 1.143       | 1.397  |
| c* SUB                          | 0.012     | 0.018 | 0.305       | 0.457  |
| c* SUM                          | 0.022     | 0.028 | 0.559       | 0.711  |
| c1                              | 0.018     | 0.025 | 0.457       | 0.635  |
| c2                              | 0.045     | 0.055 | 1.143       | 1.397  |
| D                               | 0.340     | 0.380 | 8.636       | 9.652  |
| D1                              | 0.220     | 0.240 | 5.588       | 6.096  |
| D2                              | 0.038     | 0.042 | 0.965       | 1.067  |
| D3                              | 0.045     | 0.055 | 1.143       | 1.397  |
| E                               | 0.380     | 0.410 | 9.652       | 10.414 |
| E1                              | 0.245     | -     | 6.223       | -      |
| E2                              | 0.072     | 0.078 | 1.829       | 1.981  |
| <b>e</b>                        | 0.050 BSC |       | 1.27 BSC    |        |
| K                               | 0.045     | 0.055 | 1.143       | 1.397  |
| L                               | 0.575     | 0.625 | 14.605      | 15.875 |
| L1                              | 0.090     | 0.110 | 2.286       | 2.794  |
| L2                              | 0.040     | 0.055 | 1.016       | 1.397  |
| L3                              | 0.050     | 0.070 | 1.270       | 1.778  |
| L4                              | 0.010 BSC |       | 0.254 BSC   |        |
| M                               | -         | 0.002 | -           | 0.050  |
| ECN: T13-0709-Rev. B, 30-Sep-13 |           |       |             |        |
| DWG: 6006                       |           |       |             |        |



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